

Dual N-Ch 100V Fast Switching MOSFETs
Description

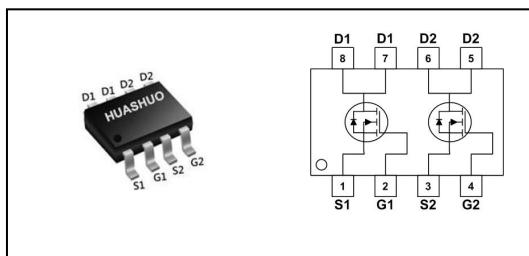
The HSM0214 is the high cell density trenched N-ch MOSFETs, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

The HSM0214 meet the RoHS and Green Product requirement with full function reliability approved.

Product Summary

V _{DS}	100	V
R _{DS(ON),max}	152	mΩ
I _D	2.3	A

- Green Device Available
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

SOP8 Pin Configuration

Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	100	V
V _{GS}	Gate-Source Voltage	±20	V
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	2.3	A
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	1.7	A
I _{DM}	Pulsed Drain Current ²	13.2	A
P _D @T _A =25°C	Total Power Dissipation ³	1.5	W
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Typ.	Max.	Unit
R _{θJA}	Thermal Resistance Junction-ambient ¹	---	85	°C/W
R _{θJC}	Thermal Resistance Junction-Case ¹	---	25	°C/W

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Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	100	---	---	V
△BV _{DSS} /△T _J	BVDSS Temperature Coefficient	Reference to 25°C , I _D =1mA	---	0.122	---	V/°C
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =2A	---	---	152	mΩ
		V _{GS} =4.5V , I _D =1A	---	---	158	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.2	---	2.5	V
△V _{GS(th)}	V _{GS(th)} Temperature Coefficient		---	-4.84	---	mV/°C
I _{DSS}	Drain-Source Leakage Current	V _{DS} =80V , V _{GS} =0V , T _J =25°C	---	---	10	uA
		V _{DS} =80V , V _{GS} =0V , T _J =55°C	---	---	100	
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V	---	---	±100	nA
g _{fs}	Forward Transconductance	V _{DS} =5V , I _D =2A	---	10.2	---	S
R _g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz	---	2.1	---	Ω
Q _g	Total Gate Charge (10V)	V _{DS} =80V , V _{GS} =10V , I _D =2A	---	18.4	---	nC
Q _{gs}	Gate-Source Charge		---	3.0	---	
Q _{gd}	Gate-Drain Charge		---	3.1	---	
T _{d(on)}	Turn-On Delay Time	V _{DD} =50V , V _{GS} =10V , R _G =3.3Ω I _D =2A	---	5.6	---	ns
T _r	Rise Time		---	20	---	
T _{d(off)}	Turn-Off Delay Time		---	28	---	
T _f	Fall Time		---	24	---	
C _{iss}	Input Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz	---	1077	---	pF
C _{oss}	Output Capacitance		---	46	---	
C _{rss}	Reverse Transfer Capacitance		---	32	---	

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I _s	Continuous Source Current ^{1,4}	V _G =V _D =0V , Force Current	---	---	2.3	A
I _{SM}	Pulsed Source Current ^{2,4}		---	---	13.2	A
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _s =1A , T _J =25°C	---	---	1.2	V

Note :

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3.The power dissipation is limited by 150°C junction temperature
- 4.The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.



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Typical Characteristics

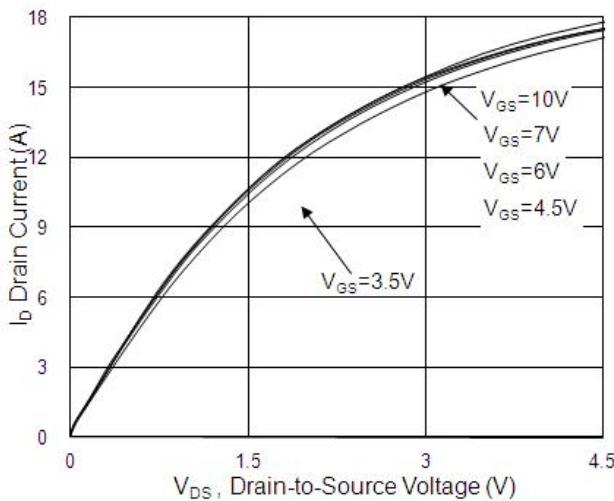


Fig.1 Typical Output Characteristics

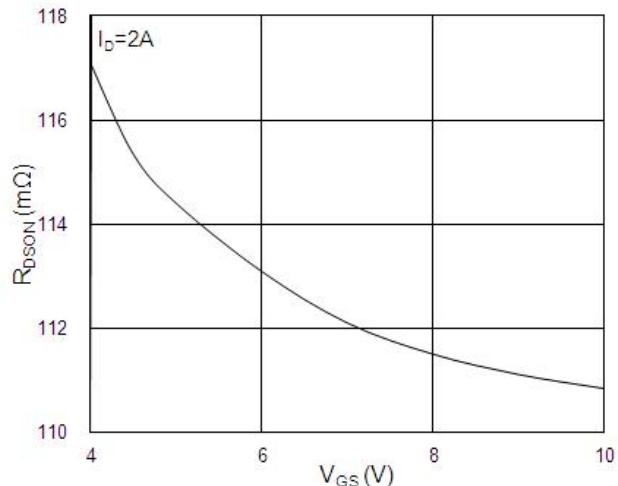


Fig.2 On-Resistance vs. Gate-Source

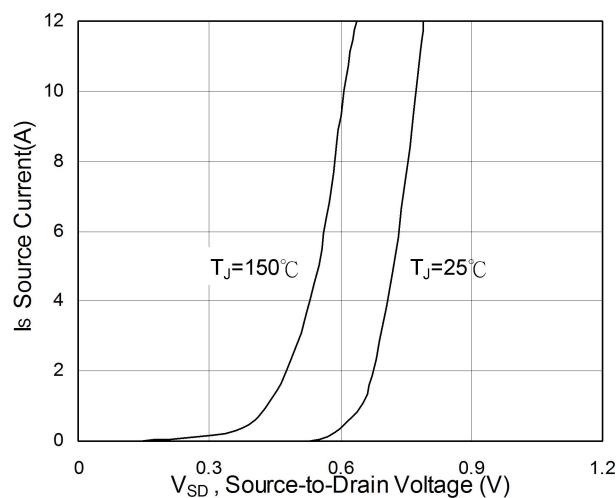


Fig.3 Forward Characteristics Of Reverse

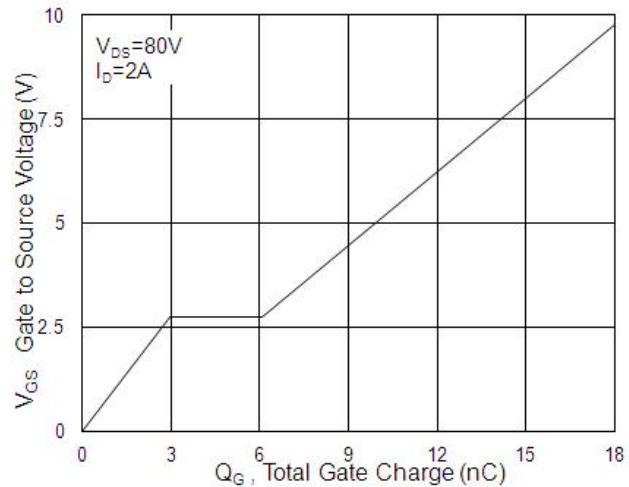


Fig.4 Gate-Charge Characteristics

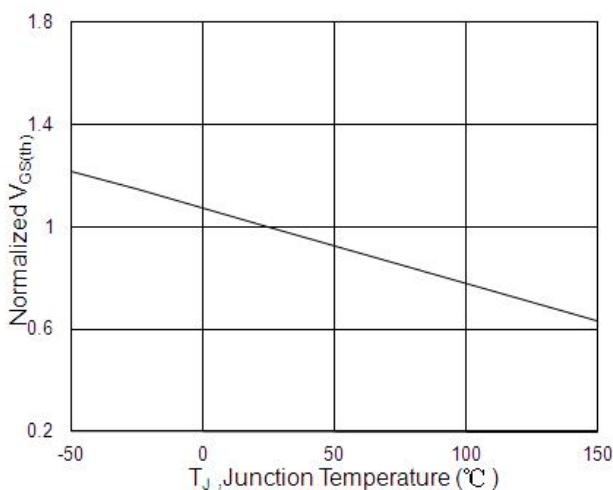


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

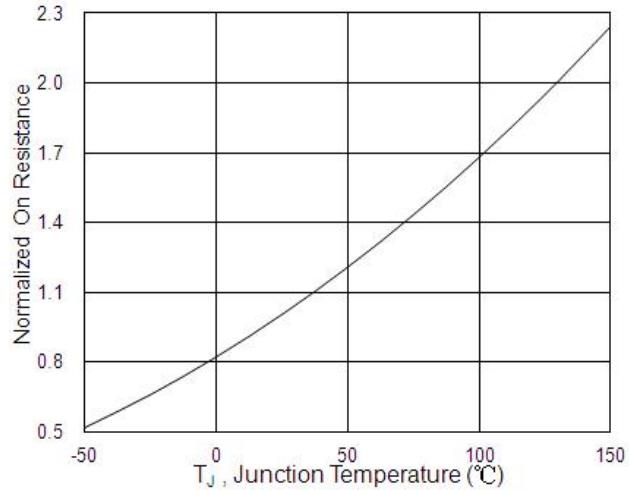


Fig.6 Normalized $R_{DS(on)}$ vs. T_J



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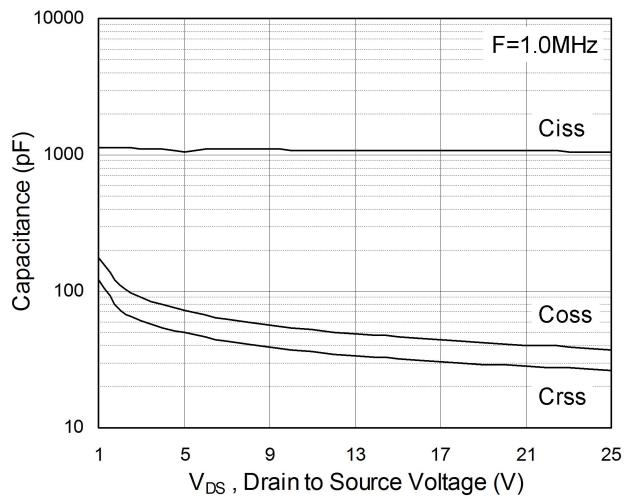


Fig.7 Capacitance

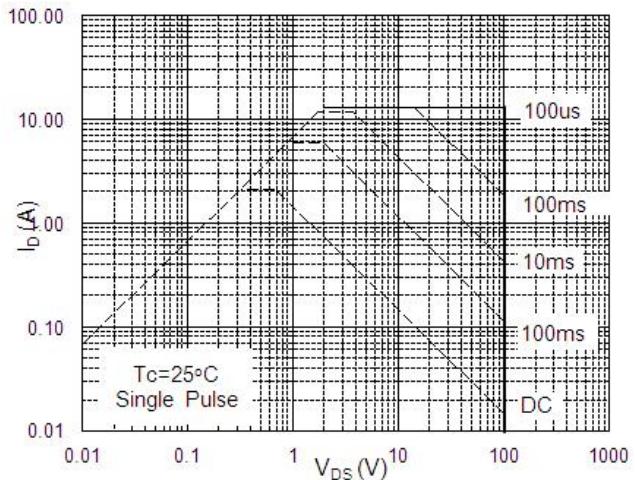


Fig.8 Safe Operating Area

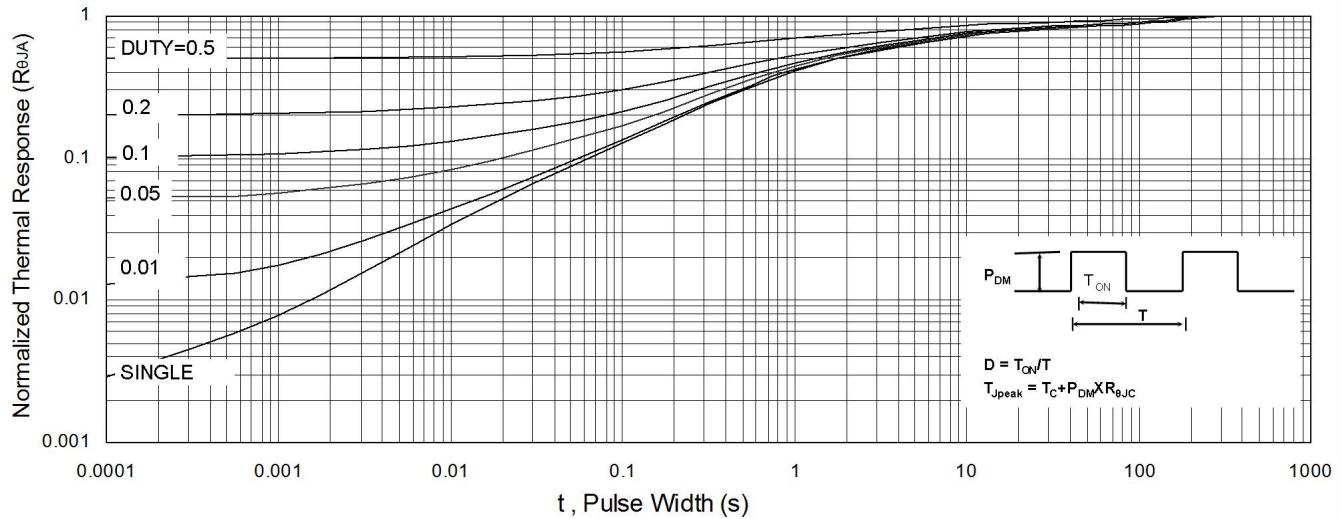


Fig.9 Normalized Maximum Transient Thermal Impedance

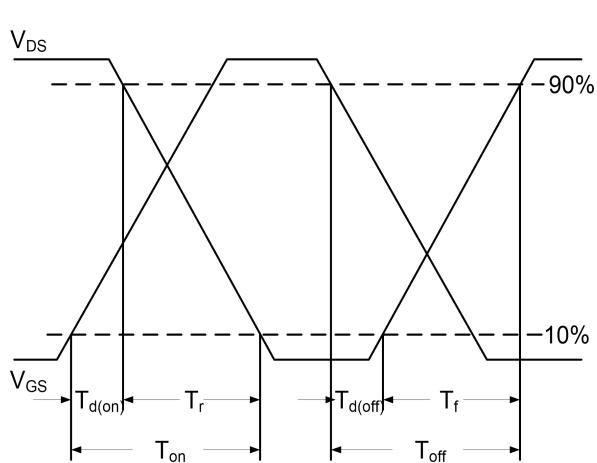


Fig.10 Switching Time Waveform

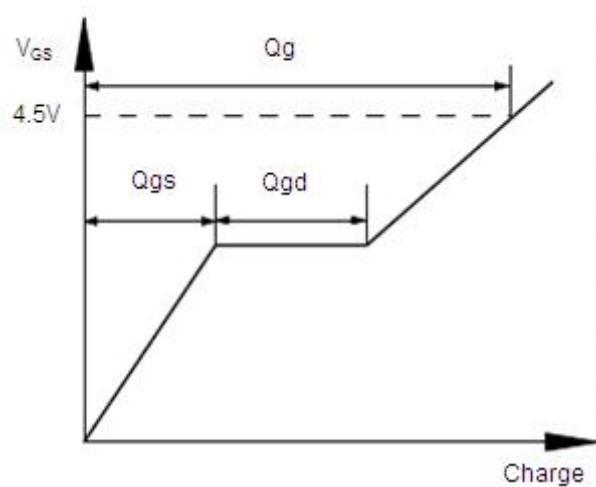


Fig.11 Gate Charge Waveform



Ordering Information

Part Number	Package code	Packaging
HSM0214	SOP-8	2500/Tape&Reel

